

Form PTO 1449 U.S. Department of Commerce Patent and Trademark Office Information Disclosure Statement by Applicant	ATTY. DOCKET NUMBER AETE.0004	SERIAL NUMBER 10/724,149
APPLICANT KUSUNOKI et al.		
FILING DATE December 1, 2003		GROUP 2828

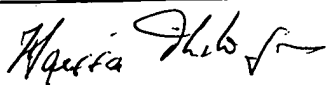
U.S. Patent Documents

Examiner Initial	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE

Foreign Patent Documents

Examiner Initial	DOCUMENT NUMBER	FILING DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION	
						Yes	No
hp	10-153979	11/26/1996	Japan	—	—	Abstract	x
hp	07-065710	08/30/1993	Japan	—	—	Abstract	x

Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)

hp		Yokoo, Kuniyoshi, et al., "Emission characteristics of metal-oxide-semiconductor electron tunneling cathode", J. Vac. Sci. Technol. B 11(2), American Vacuum Society, March/April 1993 PP429-432
hp		Negishi, Nobuyasu, et al., "High Efficiency Electron-Emission in P ⁺ /SiO ₂ /Si/Al Structure", Japan Appl. Phys. Vol. 36, 1997, PP 939-941
hp		Okamoto, Shinji "Electronic discharge from EL thin film - Thin film cold cathode", NHK Science and Technical Research Laboratories", 1994, PP 592-595 (with English translation PP 1-4)
hp		Koshida, Nobuyoshi, "Luminescence of Porous Silicon Indirectly and directly exceeding the frame of the transition", Department of Electronic and Information Engineering, Faculty of Technology, Tokyo University of Agriculture and Technology, 1997 PP 437-443, (with English translation PP 1-10)
EXAMINER		DATE CONSIDERED 12/17/04
EXAMINER: Initial if citation is considered, whether or not citation is in conformance with MPEP 609; draw a line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant		

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